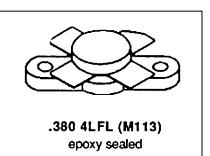




RF AND MICROWAVE TRANSISTORS VHF FM APPLICATIONS

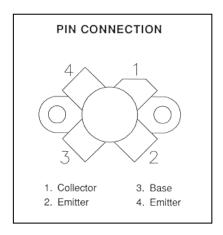
Features

- 175 MHz
- 28 VOLTS
- CLASS C
- COMMON EMITTER
- EFFICIENCY 60% MIN.
- P_{OUT} = 40 W MIN.
- G_P = 7.6 dB GAIN



DESCRIPTION:

The SD1224-02 is an epitaxial silicon NPN planar transistor designed primarily for 28 V FM Class C RF amplifiers utilized in ground station transmitters. This device utilizes ballasted emitter resistors and improved metallization systems to achieve optimum load mismatch capability.



ABSOLUTE MAXIMUM RATINGS (Tcase = 25^{\circ}C)

Symbol	Parameter	Value	Unit		
V _{CBO}	Collector-Base Voltage	65	V		
V _{CEO}	Collector-Emitter Voltage	35	V		
V _{CES}	Collector-Emitter Voltage	/oltage 65			
V _{EBO}	Emitter-Base Voltage	4.0	V		
Ic	Device Current	5.0	Α		
P _{DISS}	Power Dissipation	60	W		
TJ	Junction Temperature	+200	°C		
T _{STG}	Storage Temperature	-65 to +150	°C		

Thermal Data

D	Junction Coss Thormal Posistance	2.0	°C/M
H _{TH(j-c)}	Junction-Case Thermal Resistance	2.9	°C/W



ELECTRICAL SPECIFICATIONS (Tcase = 25^{\circ}C)

STATIC

Symbol		Test Conditions	Value		Unito	
		rest Conditions	Min.	Min. Typ. Max.	Units	
BV _{CBO}	I _C = 200 mA	I _B = 0 mA	65			V
BV _{CES}	I _C = 200 mA	$V_{BE} = 0 V$	65			V
BV _{CEO}	I _C = 100 mA	I _B = 0 mA	35			V
BV _{EBO}	I _E = 10 mA	$I_C = 0 \text{ mA}$	4.0			V
\mathbf{I}_{CBO}	V _{CB} = 30 V	I _E = 0 mA			1	mA
h _{FE}	V _{CE} = 5 V	I _C = 500 mA	20	200		

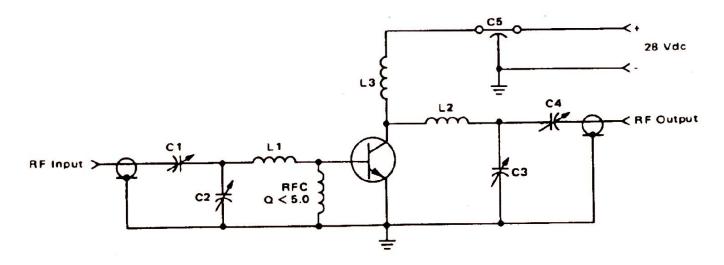
DYNAMIC

Symbol	Test Conditions		Value		l luite
	Test Conditions	Min.	Тур.	Max.	Units
P _{out}	f = 175 MHz P _{IN} = 7.0 W V _{CE}	= 28 V 40			W
ης	f = 175 MHz P _{IN} = 7.0 W V _{CE}	= 28 V 60			%
G _P	f = 175 MHz P _{IN} = 7.0 W V _{CE}	= 28 V 7.6			dB
Сов	f = 1 MHz V _{CB} = 30 V			65	рF

Revision A, October 2009



TEST CIRCUIT



C1,C2, C3,C4 : ARCO 464, 25-280pF

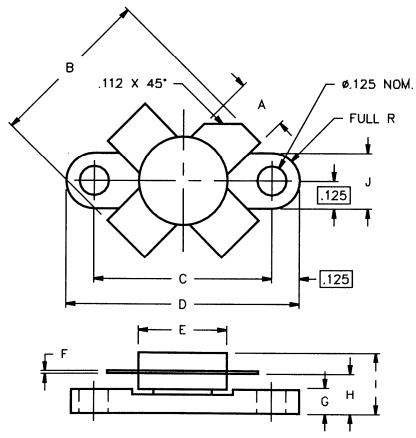
: 0.1µF

: 1" Straight #16 AWG : 1 Turn, #16 AWG, 1/4" I.D. L2

L3 : 0.22µH



PACKAGE MECHANICAL DATA



	MINIMUM INCHES/MM	MAXIMUM INCHES/MM		MINIMUM INCHES/MM	MAXIMUM INCHES/MM
Α	.220/5,59	.230/5,84			.260/7,11
В	.785/19,94		J	.240/6,10	.255/6,48
С	.720/18,29	.730/18,54			
D	.970/24,64	.980/24,89			
Ε		.385/9,78			
F	.004/0,10	.006/0,15			
G	.085/2,16	.105/2,67			
Н	.160/4,06	.180/4,57			